	Application No.	Applicant(s)		
Notice of Allowability	09/776,678	HIRABAYASH	HIRABAYASHI, YUKIYA	
	Examin r	Art Unit	1, 10.0.7.	
	Julie-Huyen L. Ngo	2871	MW	
The MAILING DATE of this communication app. All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT FOR the Office or upon petition by the applicant. See 37 CFR 1.31	S (OR REMAINS) CLOSED in 5) or other appropriate commun RIGHTS. This application is su	this application. If not in not in the notion will be mailed in	ncluded n due course. THIS	
 This communication is responsive to <u>10/30/2003</u>. The allowed claim(s) is/are <u>1-18</u>. The drawings filed on are accepted by the Examine 4. Acknowledgment is made of a claim for foreign priority of the examine of a claim for foreign priority of the examine of a claim for foreign priority of the examine of a claim for foreign priority of the examine of a claim for foreign priority of the examine of a claim for foreign priority of the examine of the exami		r (f).		
a) 🛮 All b) 🗌 Some* c) 🔲 None of the:				
1. 🖾 Certified copies of the priority documents have been received.				
2. Certified copies of the priority documents have been received in Application No				
3. Copies of the certified copies of the priority documents have been received in this national stage application from the				
International Bureau (PCT Rule 17.2(a)).				
* Certified copies not received: 5. Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application) since a specific reference was included in the first sentence of the specification or in an Application Data Sheet. 37 CFR 1.78. (a) The translation of the foreign language provisional application has been received. 6. Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121 since a specific reference was included in the first sentence of the specification or in an Application Data Sheet. 37 CFR 1.78.				
Applicant has THREE MONTHS FROM THE "MAILING DATE" of below. Failure to timely comply will result in ABANDONMENT of	of this communication to file a fifth of this application. THIS THRE	reply complying with the E-MONTH PERIOD IS	requirements noted	
7. A SUBSTITUTE OATH OR DECLARATION must be submINFORMAL PATENT APPLICATION (PTO-152) which giv			or NOTICE OF	
 8. CORRECTED DRAWINGS (as "replacement sheets") mu (a) including changes required by the Notice of Draftsper 1) hereto or 2) to Paper No (b) including changes required by the proposed drawing of the including changes required by the attached Examiner 	correction filed, which	has been approved by		
Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the margin according to 37 CFR 1.121(d).				
9. DEPOSIT OF and/or INFORMATION about the deposit attached Examiner's comment regarding REQUIREMENT FOR 1	osit of BIOLOGICAL MATE THE DEPOSIT OF BIOLOGIC	RIAL must be submitt AL MATERIAL.	ed. Note the	
Attachm nt(s)				
1⊠ Notice of References Cited (PTO-892)	5☐ Notice of Infor	mal Patent Application (PTO-152)	
 2 Notice of Draftperson's Patent Drawing Review (PTO-948) 3 Information Disclosure Statements (PTO-1449 or PTO/SB/08 Paper No. 5/7/01 & 3/7/02 4 Examiner's Comment Regarding Requirement for Deposit of Biological Material 		mary (PTO-413), Paper	No	
	^{8),} 7□ Examiner's An	nendment/Comment		
	8⊠ Examiner's Sta 9□ Other .	atement of Reasons for	Allowance	
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U.S. Patent and Trademark Office

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DETAILED ACTION

Election/Restrictions

Applicant's election with traverse of Group I, claims 1-14, on October 30, 2003 is acknowledged. The traversal is found persuasive, therefore, the restriction is hereby withdrawn and all the claims are considered and treated as set forth below.

Information Disclosure Statement

The information disclosure statements filed on May 7, 2001 and March 7, 2003 have been considered.

Priority

Receipt is acknowledged of paper submitted under 35 U.S.C. 119(a)-(d), which paper has been placed of record in the file.

Allowable Subject Matter

Claims 1-18 are allowed.

Reasons for Allowance

Claims 1, 3 and 5 are allowed since there is no prior art that either teaches or suggests a device comprising an etching stop layer having resistance to etching of an oxide film formed on a surface of a short-circuit wiring provided between the short-circuit wiring and the base oxide film in a region wider than at least a hole.

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Claim 15 is allowed since there is no prior art that either teaches or suggest a method of manufacturing a liquid crystal device comprising steps of forming an etching stop layer on the base oxide film, forming the short-circuit wiring on the base oxide film so that the short-circuit wiring crosses the etching stop layer; forming holes by etching in the insulating film above a formation region of the etching stop layer.

Claim 17 is allowed since there is no prior art that either teaches or suggest a method of manufacturing a liquid crystal device comprising steps of patterning a silicon film on the base oxide film to form the semiconductive active films and an etching stop layer; patterning the second interlayer insulating film to form holes in formation regions of the etching stop layer.

Claims 2, 4, 6-14, 16 and 18 are allowed since they depend on the allowed claims.

 Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure:

Yeo (US 6084648 A) discloses a process for fabricating the liquid crystal display with the gate line 12L is automatically separated from the shorting bar 18 because the

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connection region has such a width to allow the anodic oxide layer 13 to be formed on the whole part thereof.

Kim et al. (US 6128051 A) disclose a method for manufacturing the active panel comprising steps of forming the shorting bar connector 167 formed of the same material, i.e. aluminum or aluminum alloy, that is used to form the gate line 113a and the gate pad 115a; forming a cutting hole 165 exposing the shorting bar connector 167 is formed as shown in FIG. 4e.

Lim (US 6005647A) discloses a TFT-LCD includes a plurality of odd lines 23 and even lines 24 alternately connected to a first shorting bar 20. Cutting regions 25 separate even lines 24 from first shorting bar 20. Even lines 24, however, are connected to a second shorting bar 21a.

Contact Information

Any inquiry concerning this communication or earlier communications from the Examiner should be directed to Julie-Huyen L. Ngo whose telephone number is (703) 305-3508. The Examiner can normally be reached on T-Friday.

If attempts to reach the Examiner by telephone are unsuccessful, the Examiner's Supervisor, Mr. Robert H. Kim can be reached at (703) 305-3492.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

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Any facsimile-transmitted correspondence to this application should be faxed to the centralized facsimile number (703) 872-9306.

January 9, 2004

Julie - Huyen L. Ngo Patent Examiner Art Unit 2871